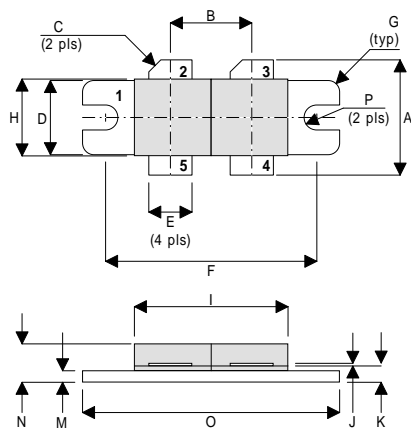


MECHANICAL DATA



DR

|       |                 |       |         |
|-------|-----------------|-------|---------|
| PIN 1 | SOURCE (COMMON) | PIN 2 | DRAIN 1 |
| PIN 3 | DRAIN 2         | PIN 4 | GATE 2  |
| PIN 5 | GATE 1          |       |         |

| DIM | Millimetres | Tol. | Inches | Tol.  |
|-----|-------------|------|--------|-------|
| A   | 19.05       | 0.50 | 0.75   | 0.020 |
| B   | 10.77       | 0.13 | 0.424  | 0.005 |
| C   | 45°         | 5°   | 45°    | 5°    |
| D   | 9.78        | 0.13 | 0.385  | 0.005 |
| E   | 5.71        | 0.13 | 0.225  | 0.005 |
| F   | 27.94       | 0.13 | 1.100  | 0.005 |
| G   | 1.52R       | 0.13 | 0.060R | 0.005 |
| H   | 10.16       | 0.13 | 0.400  | 0.005 |
| I   | 22.22       | MAX  | 0.875  | MAX   |
| J   | 0.13        | 0.02 | 0.005  | 0.001 |
| K   | 2.72        | 0.13 | 0.107  | 0.005 |
| M   | 1.70        | 0.13 | 0.067  | 0.005 |
| N   | 5.08        | 0.50 | 0.200  | 0.020 |
| O   | 34.03       | 0.13 | 1.340  | 0.005 |
| P   | 1.61R       | 0.08 | 0.064R | 0.003 |

**GOLD METALLISED  
MULTI-PURPOSE SILICON  
DMOS RF FET  
350W – 50V – 175MHz  
PUSH-PULL**

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- LOW  $C_{rss}$
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN – 13 dB MINIMUM

APPLICATIONS

- VHF/UHF COMMUNICATIONS  
from 1 MHz to 200 MHz

ABSOLUTE MAXIMUM RATINGS ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

|              |  |              |
|--------------|--|--------------|
| $P_D$        | Power Dissipation                      | 438W         |
| $BV_{DSS}$   | Drain – Source Breakdown Voltage*      | 125V         |
| $BV_{GSS}$   | Gate – Source Breakdown Voltage*       | ±20V         |
| $I_{D(sat)}$ | Drain Current*                         | 21A          |
| $T_{stg}$    | Storage Temperature                    | -65 to 150°C |
| $T_j$        | Maximum Operating Junction Temperature | 200°C        |

\* Per Side

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## ELECTRICAL CHARACTERISTICS (T<sub>case</sub> = 25°C unless otherwise stated)

| Parameter                |   | Test Conditions                              |                                   | Min. | Typ. | Max. | Unit |
|--------------------------|---|--|-----------------------------------|------|------|------|------|
| <b>PER SIDE</b>          |   |  |                                   |      |      |      |      |
| B <sub>V</sub> DSS       | Drain–Source Breakdown Voltage                | V <sub>GS</sub> = 0                          | I <sub>D</sub> = 100mA            | 125  |      |      | V    |
| I <sub>D</sub> DSS       | Zero Gate Voltage Drain Current               | V <sub>DS</sub> = 50V                        | V <sub>GS</sub> = 0               |      |      | 7    | mA   |
| I <sub>G</sub> DSS       | Gate Leakage Current                          | V <sub>GS</sub> = 20V                        | V <sub>DS</sub> = 0               |      |      | 1    | μA   |
| V <sub>GS(th)</sub>      | Gate Threshold Voltage*                       | I <sub>D</sub> = 10mA                        | V <sub>DS</sub> = V <sub>GS</sub> | 1    |      | 7    | V    |
| g <sub>fs</sub>          | Forward Transconductance*                     | V <sub>DS</sub> = 10V                        | I <sub>D</sub> = 3.5A             | 5.6  |      |      | mhos |
| V <sub>GS(th)match</sub> | Gate Threshold Voltage Matching Between Sides | I <sub>D</sub> = 10mA                        | V <sub>DS</sub> = V <sub>GS</sub> |      |      | 0.1  | V    |
| <b>TOTAL DEVICE</b>      |   |  |                                   |      |      |      |      |
| G <sub>PS</sub>          | Common Source Power Gain                      | P <sub>O</sub> = 350W                        |                                   | 13   |      |      | dB   |
| η                        | Drain Efficiency                              | V <sub>DS</sub> = 50V I <sub>DQ</sub> = 1.4A |                                   | 50   |      |      | %    |
| VSWR                     | Load Mismatch Tolerance                       | f = 175MHz                                   |                                   | 20:1 |      |      | —    |
| <b>PER SIDE</b>          |   |  |                                   |      |      |      |      |
| C <sub>iss</sub>         | Input Capacitance                             | V <sub>DS</sub> = 50V                        | V <sub>GS</sub> = -5V f = 1MHz    |      |      | 420  | pF   |
| C <sub>oss</sub>         | Output Capacitance                            | V <sub>DS</sub> = 50V                        | V <sub>GS</sub> = 0 f = 1MHz      |      |      | 175  | pF   |
| C <sub>rss</sub>         | Reverse Transfer Capacitance                  | V <sub>DS</sub> = 50V                        | V <sub>GS</sub> = 0 f = 1MHz      |      |      | 10.5 | pF   |

\* Pulse Test: Pulse Duration = 300 μs , Duty Cycle ≤ 2%

## HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

**THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.**

## THERMAL DATA

|                       |                                    |                |
|-----------------------|------------------------------------|----------------|
| R <sub>THj-case</sub> | Thermal Resistance Junction – Case | Max. 0.4°C / W |
|-----------------------|------------------------------------|----------------|

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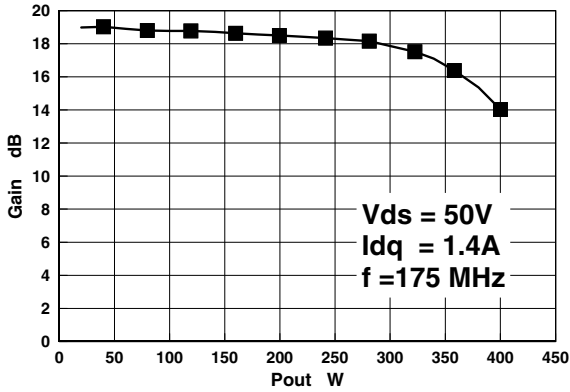


Figure 1 – Gain vs. Output Power.

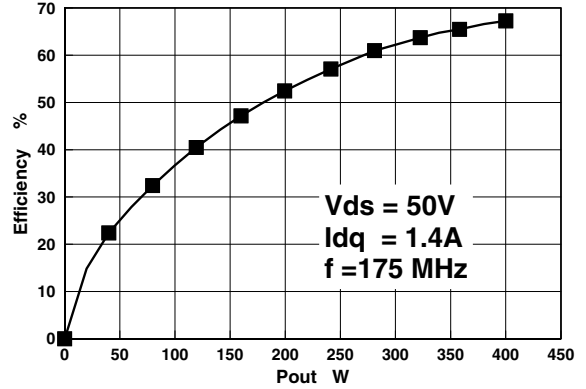


Figure 2 – Efficiency vs. Output Power.

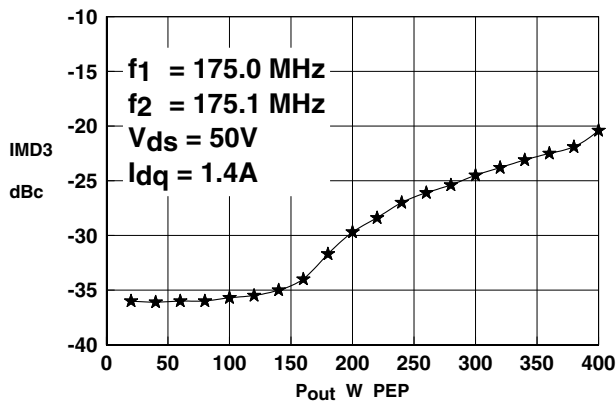


Figure 3 – IMD vs. Output Power.

### D5029UK OPTIMUM SOURCE AND LOAD IMPEDANCE @ 350W / 50V

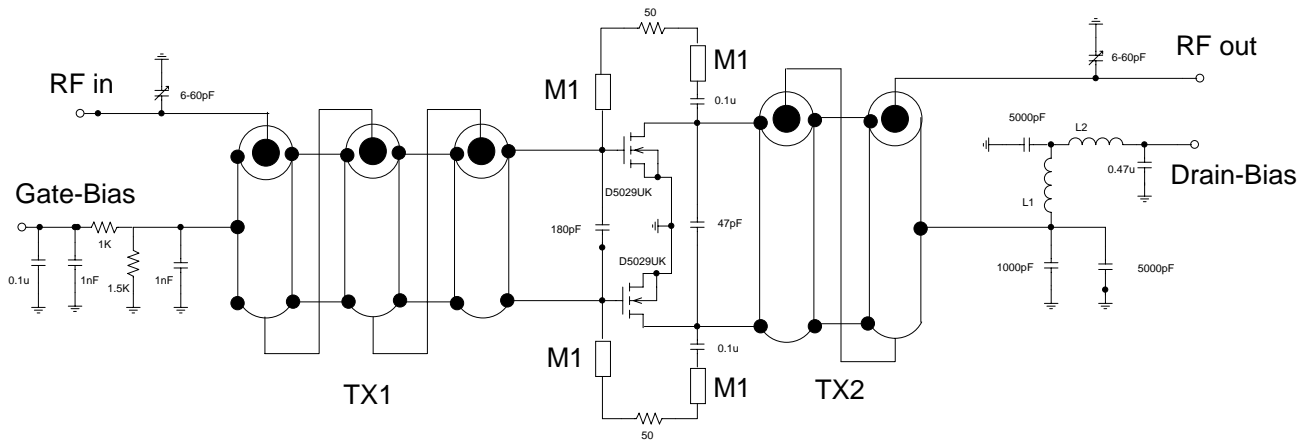
| Frequency<br>MHz | Z <sub>S</sub><br>Ω | Z <sub>L</sub><br>Ω |
|------------------|---------------------|---------------------|
| 175              | 1.0 + j1.2          | 2.6 + j1.3          |

### Typical S Parameters

! V<sub>DS</sub> = 50V, I<sub>DQ</sub> = 1.4A  
# MHz S MA R 50

| Freq<br>MHz | S11  |        | S21   |      | S12   |      | S22  |        |
|-------------|------|--------|-------|------|-------|------|------|--------|
|             | mag  | ang    | mag   | ang  | mag   | ang  | mag  | ang    |
| 50          | 0.83 | -165.3 | 20.29 | 69.4 | 0.007 | -9.2 | 0.63 | -150.7 |
| 100         | 0.89 | -170.0 | 8.28  | 48.6 | 0.004 | -6.0 | 0.78 | -156.6 |
| 150         | 0.93 | -173.2 | 4.42  | 35.6 | 0.003 | 50.0 | 0.86 | -162.0 |
| 200         | 0.95 | -175.7 | 2.71  | 27.2 | 0.005 | 82.4 | 0.91 | -166.2 |
| 250         | 0.97 | -177.8 | 1.82  | 21.3 | 0.008 | 88.8 | 0.94 | -169.4 |
| 300         | 0.98 | -179.7 | 1.30  | 17.0 | 0.011 | 90.0 | 0.95 | -171.9 |
| 350         | 0.98 | -178.7 | 0.97  | 13.8 | 0.014 | 89.6 | 0.97 | -174.0 |
| 400         | 0.98 | 177.3  | 0.76  | 11.4 | 0.017 | 88.9 | 0.97 | -175.7 |
| 450         | 0.99 | 175.9  | 0.61  | 9.5  | 0.020 | 87.9 | 0.98 | -177.3 |
| 500         | 0.99 | 174.7  | 0.50  | 8.1  | 0.023 | 86.9 | 0.98 | -178.6 |
| 550         | 0.99 | 173.5  | 0.42  | 7.1  | 0.026 | 85.9 | 0.98 | -179.8 |
| 600         | 0.99 | 172.3  | 0.35  | 6.5  | 0.028 | 84.9 | 0.99 | 179.0  |

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TX1 9:1 transformer. 3 turns of 062-25 semi-rigid coax around 75-26 powdered iron core

TX2 4:1 transformer. 2 turns of 090-25 semi-rigid coax around 100-8 powdered iron core

L1 10 turns 16 awg enamelled wire, 5mm internal diameter

L2 0.5 turns 16 awg enamelled wire on A1 x 1 2-hole core

M1 microstrip line, 20mm long, 1mm wide on 0.062in thick G10 substrate

## D5029UK 175MHz TEST FIXTURE